IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PATENT JCE U.S. PTO

REQUEST FOR FILING APPLICATION

Under Rule 53(a), (b) & (f)

(No Filing Fee or Oath/Declaration)

(Do NOT use for Provisional or PCT Applications) Use for Design or Utility Applications



EL00028CDC

Hon. Commissioner of Patents Washington, DC 20231

RULE 53(f) NO DECLARATION

Atty. Dkt.

P 2800192

Washington, DC 20231			M#	Client Ref				
Sir:		Date:	April 17, 200	1				
1. This is a Request for filing a new Patent Application(Design Utility) entitled:								
2. (Complete) Title: FABRICATING PROCESS OF A SEMICONDUCTOR DEVICE INCLUDING A CVD PROCESS OF A METAL FILM without a filing fee or Oath/Declaration but for which is enclosed the following:								
3. ☑ Abstract 1 p		Declaration but for which is	enciosea the	e tollowing: 😝 📱				
3. ⊠ Abstract1 p	page(s).							
 4. 24 Pages of Specification (only spec. and claims); 5. Specification in non-English language 14 Numbered claim(s); and 								
	_							
	sheet(s)		nal of size:	⊠A4				
DOMESTIC/INTERNATIONAL priority is claimed under 35 USC 119(e)/120/365(c) based on the following provisional, nonprovisional and/or PCT international application(s):								
Application No.	Filing Date	Application No.	F	iling Date				
(1)		(2)						
(3) (5)		(4)						
## P								
FOREIGN priority is claimed under 35 USC 119(a)-(d)/365(b) based on filing in JAPAN								
Application No.	Filing Date	Application No.	F	iling Date				
(1) 2000-115187 (3)	April 17, 2000	(2)						
(5)		(4) See 3 rd page for addition	nal priorities					
		occ o page for additive	onal priorities)				
1 (No.) Certified copy (copies):								
 This is a reissue of Patent No. See top first page re prior Provisional, National, International application(s) (X box only if info is there and do not complete item 14 or 15.) This application claims benefit of the following prior US application(s), the contents of which are incorporated into this application by this reference: 								
No								
	/ filed							
No	/ filed							
No. PCT Designated the U.S. and that Ir English	/ filed nternational Application was	s 🗌 was not publish	ned under PC	, which CT Acticle 21(2) in				
	reliminary Amendment, which ons	amends the specification to	claim benef	it of the above				
16. Extension to date:	concurrently filed	not needed previo	ously filed					
7.								
17(a) Attached: (No.) Small Entity Statement(s). (Since 9/8/00 Small Entity Statement not essential to make claim)								
7(b) See NONPUBLICATION REQUEST under Rule 213(a) attached (Pat-258)								

18. 🗌 As	18. Assignee (optional):								
40 🗆 🗛									
19. L At	19. Attached:								
20. This application is made by the following named inventor(s) (Listing of inventor(s) not a requirement, but list if known)									
	(Listing of inventor(s) <u>not</u> a requirement, but list if known)								
(1) Inventor Tomohisa		HOSINO							
Posidonos	Miropolsi obi '	First	Middle Initial	· ,	Family Name				
Residence	Nirasaki-shi,		JAPAN	<u> </u>	JAPAN				
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(include Zip Code)									
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(2) 111011101	VIIIOCITE	First	Middle Initial	<u> </u>					
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(include Zin (Yamanashi, JAPAN (include Zip Code)								
Just	50dc)	<u> </u>							
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(include Zip C	Code)								
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(include Zip C									
21. NOTE: FOR ADDITIONAL INVENTORS, "X" and list additional inventors on attached sheet (incorporated by reference) Pillsbury Winthrop LLP Intellectual Property Group 00909									
		By: Atty:	Glenn J. Perry		Reg. No28458				
Atty/Sec: gjp/mj		Sig:	cate with 2 post card re	erints (PAT-103)	Fax: (202) 822-0944 Tel: (202) 861-3070				
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